

## iscN-Channel MOSFET Transistor

TK6R7P06PL

## • FEATURES

- Low drain-source on-resistance:  
 $R_{DS(ON)} = 6.7\text{m}\Omega$  (MAX) ( $V_{GS} = 10\text{ V}$ )
- Enhancement mode:  
 $V_{th} = 1.5$  to  $2.5\text{V}$  ( $V_{DS} = 10\text{ V}$ ,  $I_D=0.3\text{mA}$ )
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## • DESCRIPTION

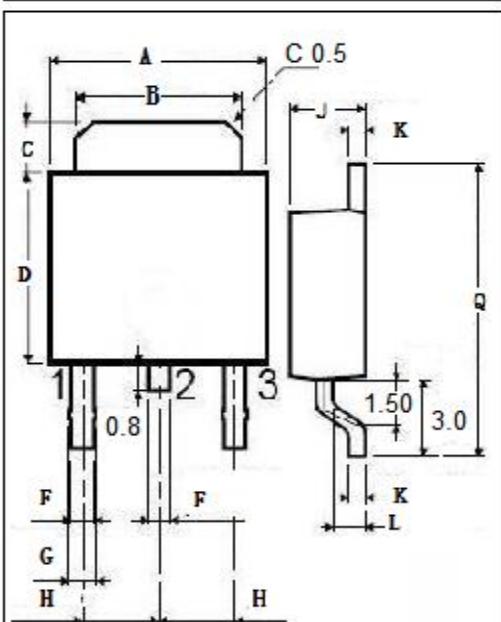
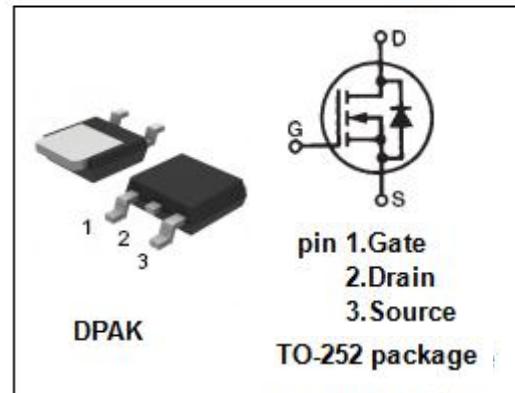
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	60	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous	46	A
$I_{DM}$	Drain Current-Single Pulsed	190	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$	66	W
$T_j$	Max. Operating Junction Temperature	175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~175	$^\circ\text{C}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	2.24	$^\circ\text{C}/\text{W}$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

**iscN-Channel MOSFET Transistor****TK6R7P06PL****ELECTRICAL CHARACTERISTICS**T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	60			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =0.3mA	1.5		2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =23A			6.7	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V			±0.1	µA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 60V; V <sub>GS</sub> = 0V			10	µA
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =46A, V <sub>GS</sub> = 0 V			1.5	V

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